

PNP Multi-Chip General-Purpose Amplifier

FFB2907A, FMB2907A, MMPQ2907A

Description

This device is designed for use as a general-purpose amplifier and switch for collector currents to 500 mA. Sourced from Process 63.

Internal Connections

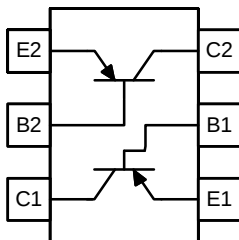


Figure 1. FFB2907A

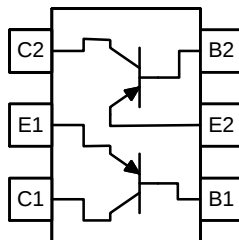


Figure 2. FMB2907A

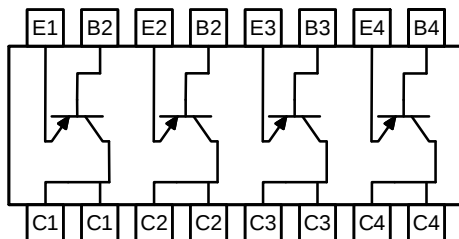


Figure 3. MMPQ2907A

ABSOLUTE MAXIMUM RATINGS (Note 1, 2)

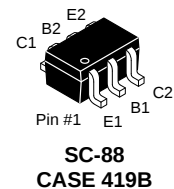
(T_A = 25 °C, unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{CBO}	Collector-Base Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-5.0	V
I _C	Collector Current – Continuous	-600	mA
T _J , T _{STG}	Junction and Storage Temperature	-55 to +150	°C

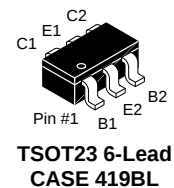
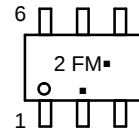
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.

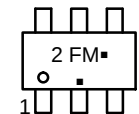
MARKING DIAGRAM



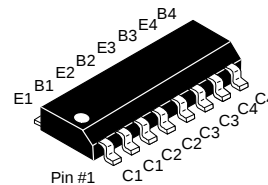
FFB2907A



FMB2907A



2F = Specific Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)



SOIC-16, 150 mils
CASE 751BG

MMPQ2907A



MMPQ2907A = Specific Device Code
A = Assembly Site
WL = Wafer Lot Number
Y = Year of Production
WW = Work Week Number

ORDERING INFORMATION

Device	Package	Shipping [†]
FFB2907A	SC-88 (Pb-Free, Halide Free)	3000 / Tape & Reel
FMB2907A	TSOT23 (Pb-Free, Halide Free)	3000 / Tape & Reel
MMPQ2907A	SOIC-16 (Pb-Free, Halide Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](http://www.onsemi.com/BRD8011/D).

FFB2907A, FMB2907A, MMPQ2907A

THERMAL CHARACTERISTICS (Note 3) ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Symbol	Parameter	Max			Unit
		FFB2907A	FMB2907A	MMPQ2907A	
P_D	Total Device Dissipation	300	700	1,000	mW
	Derate Above $25\text{ }^{\circ}\text{C}$	2.4	5.6	8.0	mW/ $^{\circ}\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	415	180	–	$^{\circ}\text{C/W}$
	Thermal Resistance, Junction to Ambient, Effective 4 Die	–	–	125	
	Thermal Resistance, Junction to Ambient, Each Die	–	–	240	

3. PCB size: FR-4 76 x 114 x 1.57 mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

ELECTRICAL CHARACTERISTICS (Note 4) ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (Note 4)	$I_C = -10\text{ mA}$, $I_B = 0$	-60	–	–	V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -10\text{ }\mu\text{A}$, $I_E = 0$	-60	–	–	V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -10\text{ }\mu\text{A}$, $I_C = 0$	-5.0	–	–	V
I_{BL}	Base Cut-Off Current	$V_{CE} = -30\text{ V}$, $V_{EB} = -0.5\text{ V}$	–	–	-50	nA
I_{CEX}	Collector Cut-Off Current	$V_{CE} = -30\text{ V}$, $V_{EB} = -0.5\text{ V}$	–	–	-50	nA
I_{CBO}	Collector Cut-Off Current	$V_{CB} = -50\text{ V}$, $I_E = 0$	–	–	-0.02	μA
		$V_{CB} = -50\text{ V}$, $I_E = 0$, $T_A = 125\text{ }^{\circ}\text{C}$	–	–	-20	
h_{FE}	DC Current Gain	$I_C = -0.1\text{ mA}$, $V_{CE} = -10\text{ V}$	75	–	–	
		$I_C = -1.0\text{ mA}$, $V_{CE} = -10\text{ V}$	100	–	–	
		$I_C = -10\text{ mA}$, $V_{CE} = -10\text{ V}$	100	–	–	
		$I_C = -150\text{ mA}$, $V_{CE} = -10\text{ V}$ (Note 4)	100	–	300	
		$I_C = -500\text{ mA}$, $V_{CE} = -10\text{ V}$ (Note 4)	50	–	–	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage (Note 4)	$I_C = -150\text{ mA}$, $I_B = -15\text{ mA}$	–	–	-0.4	V
		$I_C = -500\text{ mA}$, $I_B = -50\text{ mA}$	–	–	-1.6	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -150\text{ mA}$, $I_B = -15\text{ mA}$ (Note 4)	–	–	-1.3	V
		$I_C = -500\text{ mA}$, $I_B = -50\text{ mA}$	–	–	-2.6	
f_T	Current Gain-Bandwidth Product	$I_C = -50\text{ mA}$, $V_{CE} = -20\text{ V}$, $f = 100\text{ MHz}$	–	250	–	MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{ V}$, $I_E = 0$, $f = 100\text{ kHz}$	–	6.0	–	pF
C_{ib}	Input Capacitance	$V_{EB} = -2.0\text{ V}$, $I_C = 0$, $f = 100\text{ kHz}$	–	12	–	pF
t_{on}	Turn-On Time	$V_{CC} = -30\text{ V}$, $I_C = -150\text{ mA}$, $I_{B1} = -15\text{ mA}$	–	30	–	ns
t_d	Delay Time		–	8	–	ns
t_r	Rise Time		–	20	–	ns
t_{off}	Turn-Off Time	$V_{CC} = -6.0\text{ V}$, $I_C = -150\text{ mA}$, $I_{B1} = I_{B2} = -15\text{ mA}$	–	80	–	ns
t_s	Storage Time		–	60	–	ns
t_f	Fall Time		–	20	–	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse test: pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2.0\%$.

TYPICAL PERFORMANCE CHARACTERISTICS

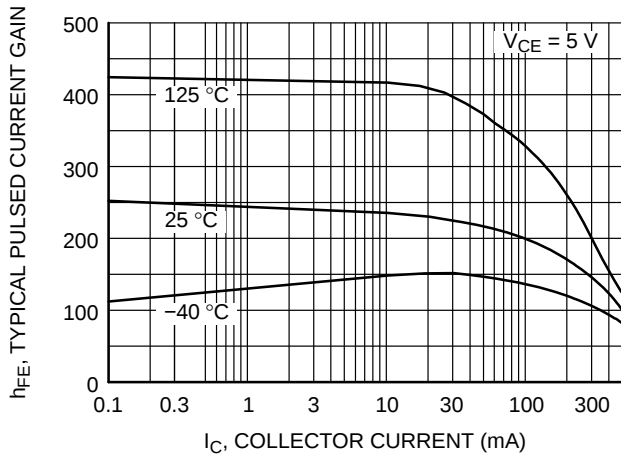


Figure 4. Typical Pulsed Current Gain vs. Collector Current

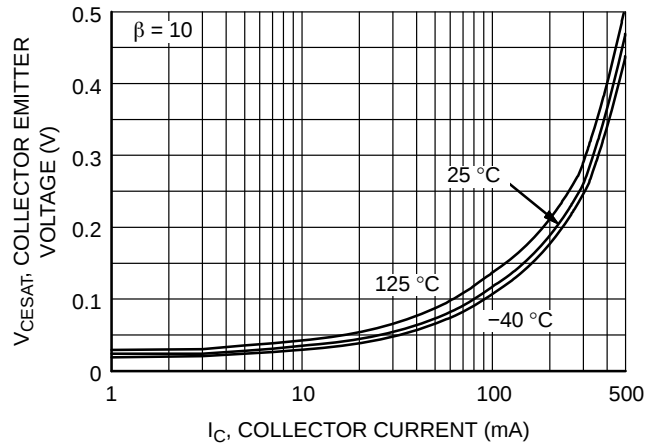


Figure 5. Collector-Emitter Saturation Voltage vs. Collector Current

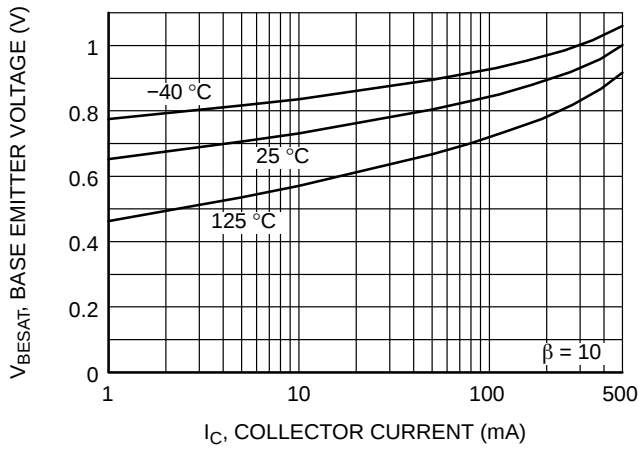


Figure 6. Base-Emitter Saturation Voltage vs. Collector Current

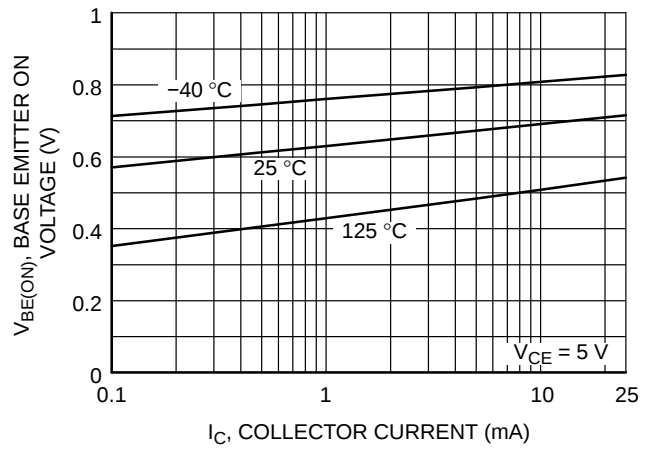


Figure 7. Base-Emitter On Voltage vs. Collector Current

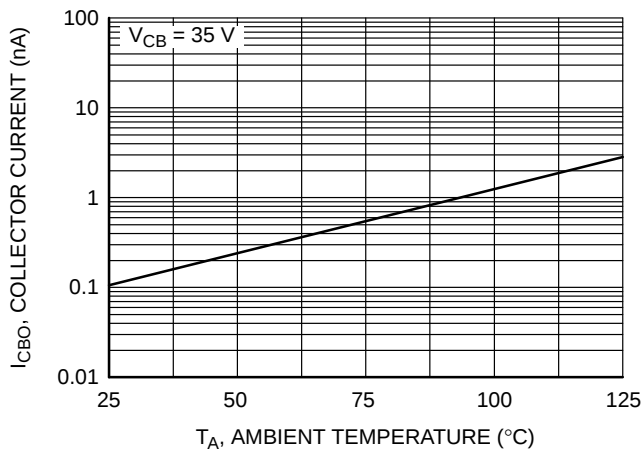


Figure 8. Collector Cut-Off Current vs. Ambient Temperature

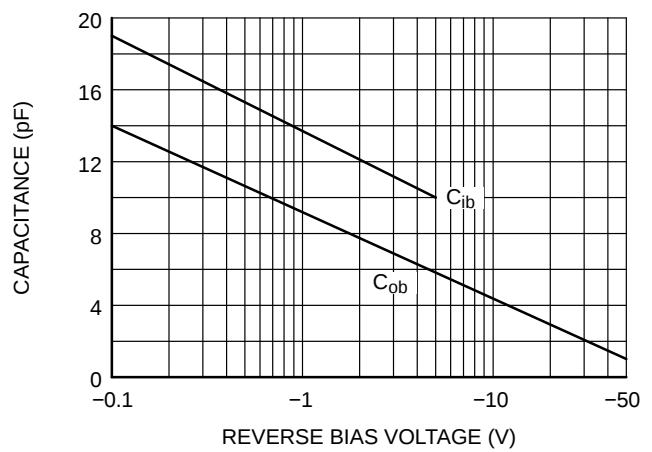


Figure 9. Input and Output Capacitance vs. Reverse Bias Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

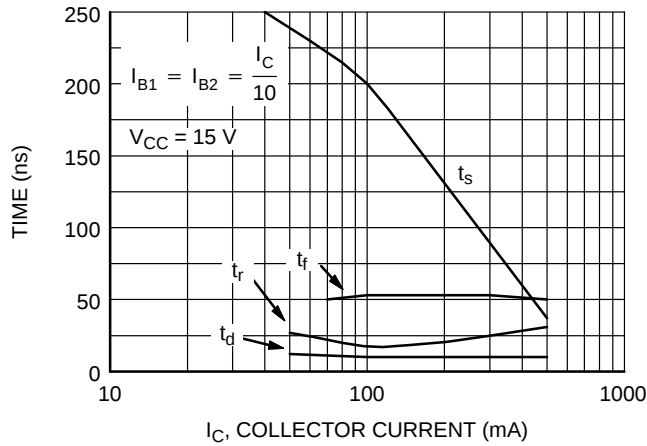


Figure 10. Switching Times vs. Collector Current

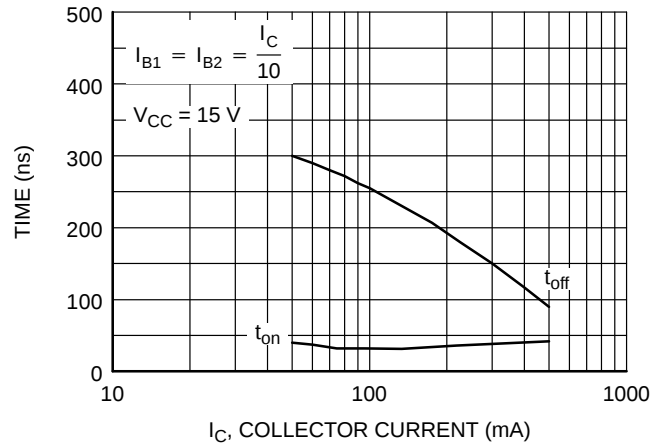


Figure 11. Turn-On and Turn-Off Times vs. Collector Current

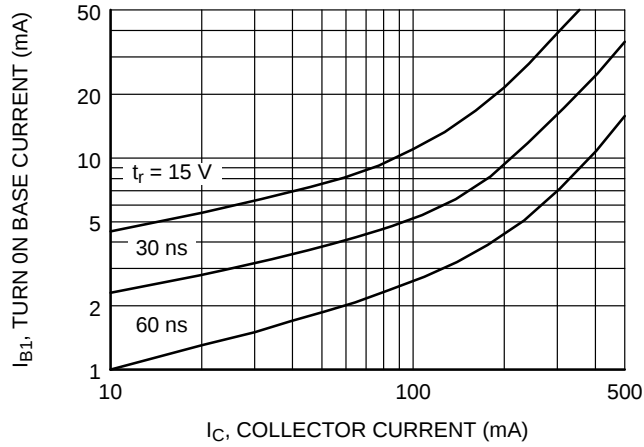


Figure 12. Rise Time vs. Collector and Turn-On Base Current

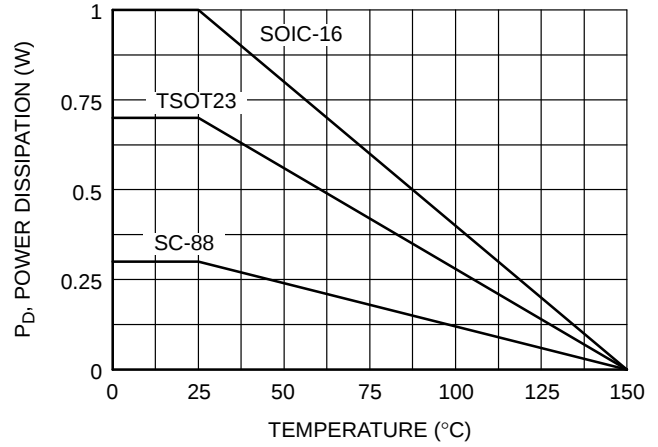


Figure 13. Power Dissipation vs. Ambient Temperature

FFB2907A, FMB2907A, MMPQ2907A

REVISION HISTORY

Revision	Description of Changes	Date
2	Converted the Data Sheet to onsemi format.	1/16/2025
3	Updated the Case Outline from 419AG to 419BL.	5/13/2025



SCALE 2:1

TSOT23 6-Lead
CASE 419BL
ISSUE A

DATE 31 AUG 2020



TOP VIEW



FRONT VIEW



DETAIL A



SIDE VIEW

SYMM


LAND PATTERN
RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR
PB-FREE STRATEGY AND SOLDERING DETAILS,
PLEASE DOWNLOAD THE ON SEMICONDUCTOR
SOLDERING AND MOUNTING TECHNIQUES
REFERENCE MANUAL, SOLDERM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.25MM PER END. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
4. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.00	0.05	0.10
A2	0.70	0.85	1.00
A3	0.25 BSC		
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.80	2.95	3.10
d	0.30 REF		
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e	0.95 BSC		
e1	1.90 BSC		
L1	0.60 REF		
L2	0.20	0.40	0.60
Θ	0°	—	10°

GENERIC
MARKING DIAGRAM*


XXX = Specific Device Code

M = Date Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON83292G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSOT23 6-Lead	PAGE 1 OF 1

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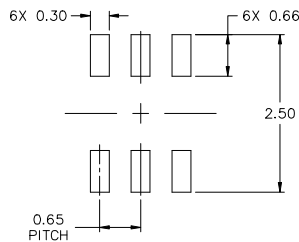


SC-88 2.00x1.25x0.90, 0.65P
CASE 419B-02
ISSUE Z

DATE 18 APR 2024

NOTES:

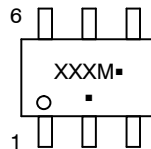
1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.



RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	---	---	1.10
A1	0.00	---	0.10
A2	0.70	0.90	1.00
b	0.15	0.20	0.25
c	0.08	0.15	0.22
D	2.00 BSC		
E	2.10 BSC		
E1	1.25 BSC		
e	0.65 BSC		
L	0.26	0.36	0.46
L2	0.15 BSC		
aaa	0.15		
bbb	0.30		
ccc	0.10		
ddd	0.10		

STYLES ON PAGE 2

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SC-88 2.00x1.25x0.90, 0.65P
CASE 419B-02
ISSUE Z

DATE 18 APR 2024

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13: PIN 1. ANODE 2. N/C 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 14: PIN 1. VREF 2. GND 3. GND 4. IOUT 5. VEN 6. VCC	STYLE 15: PIN 1. ANODE 1 2. ANODE 2 3. ANODE 3 4. CATHODE 3 5. CATHODE 2 6. CATHODE 1	STYLE 16: PIN 1. BASE 1 2. EMITTER 2 3. COLLECTOR 2 4. BASE 2 5. EMITTER 1 6. COLLECTOR 1	STYLE 17: PIN 1. BASE 1 2. EMITTER 1 3. COLLECTOR 2 4. BASE 2 5. EMITTER 2 6. COLLECTOR 1	STYLE 18: PIN 1. VIN1 2. VCC 3. VOUT2 4. VIN2 5. GND 6. VOUT1
STYLE 19: PIN 1. I OUT 2. GND 3. GND 4. V CC 5. V EN 6. V REF	STYLE 20: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 21: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. N/C 6. CATHODE 1	STYLE 22: PIN 1. D1 (i) 2. GND 3. D2 (i) 4. D2 (c) 5. VBUS 6. D1 (c)	STYLE 23: PIN 1. Vn 2. CH1 3. Vp 4. N/C 5. CH2 6. N/C	STYLE 24: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 25: PIN 1. BASE 1 2. CATHODE 3. COLLECTOR 2 4. BASE 2 5. EMITTER 6. COLLECTOR 1	STYLE 26: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1	STYLE 27: PIN 1. BASE 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. EMITTER 2 6. COLLECTOR 2	STYLE 28: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 29: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE/ANODE 6. CATHODE	STYLE 30: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1

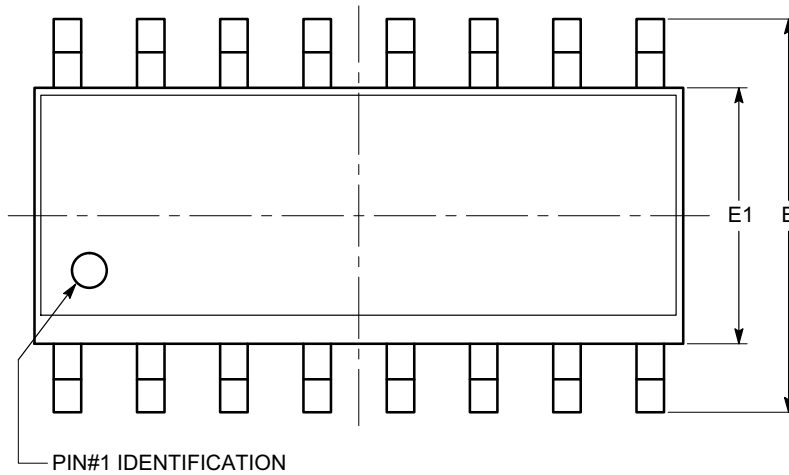
Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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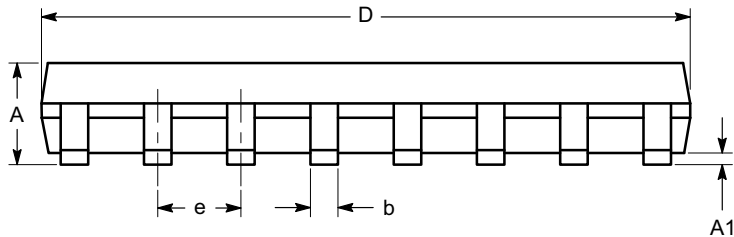
SOIC-16, 150 mils
CASE 751BG
ISSUE O

DATE 19 DEC 2008

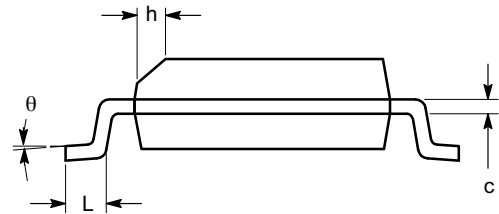


SYMBOL	MIN	NOM	MAX
A	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
c	0.19		0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27 BSC		
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

TOP VIEW



SIDE VIEW



END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-012.

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